Rectifier diodes schottky barrier

PBYR745B series

GENERAL DESCRIPTION

Low leakage, platinum barrier, schottky rectifier diodes in a plastic envelope suitable for surface mounting, featuring low forward voltage drop, absence of stored charge. and guaranteed reverse surge capability. The devices are intended for use in switched mode power supplies and high frequency circuits in general where low conduction and zero switching losses are important.

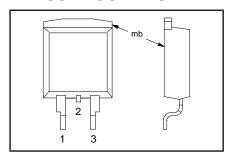
QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
V _{RRM}	PBYR7- Repetitive peak reverse voltage	35B 35	40B 40	45B 45	V
$I_{F(AV)}$	Forward voltage Average forward current	0.57 7.5	0.57 7.5	0.57 7.5	V A

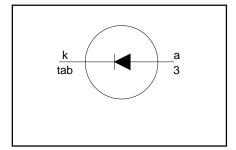
PINNING - SOT404

PIN	DESCRIPTION	
1	no connection	
2	cathode	
3	anode	
mb	cathode	

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.		MAX.		UNIT
V _{RRM} V _{RWM} V _R	Repetitive peak reverse voltage Crest working reverse voltage Continuous reverse voltage	T _{mb} ≤ 139 °C		-35 35 35 35	-40 40 40 40	-45 45 45 45	> >
I _{F(AV)}	Average forward current	square wave; $\delta = 0.5$; $T_{mb} \le 136 ^{\circ}C$	-		7.5		A
I _{F(RMS)} I _{FRM}	RMS forward current Repetitive peak forward current Non-repetitive peak forward	$t = 25 \mu s; \delta = 0.5;$ $T_{mb} \le 136 ^{\circ}C$ t = 10 ms	-		11 15 135		A A A
	current	t = 8.3 ms sinusoidal; T_j = 125 °C prior to surge; with reapplied $V_{RRM(max)}$	-		150		A
l ² t	I ² t for fusing	t = 10 ms	-		91		A ² s
I _{RRM} I _{RSM}	Repetitive peak reverse current Non-repetitive peak reverse current	$t_p = 2 \mu s; \delta = 0.001$ $t_p = 100 \mu s$	-		1		A A
T_{stg} T_{i}	Storage temperature Operating junction temperature		-65 -		175 150		°C °C

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THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb}	Thermal resistance junction to		-	1	3.0	K/W
R _{th j-a}	mounting base Thermal resistance junction to ambient	minimum footprint, FR4 board	-	50	-	K/W

STATIC CHARACTERISTICS

 $T_j = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{F}	Forward voltage	I _F = 7.5 A; T _j = 125°C I _F = 15 A; T _i = 125°C	-	0.50	0.57	V
			-	0.62	0.72	V
		I _F = 15 A	-	0.74	0.84	V
l _R	Reverse current	$V_R = V_{RRM}$	-	50	100	μΑ
		$V_{R} = V_{RRM}$; $T_{i} = 125 ^{\circ}C$	-	12	22	mΑ
C _d	Junction capacitance	$V_R = V_{RRM}^{NNM}$; $T_j = 125 ^{\circ}C$ $f = 1MHz$; $V_R = 5V$; $T_j = 25 ^{\circ}C$ to	-	350	-	pF
		125 °C				

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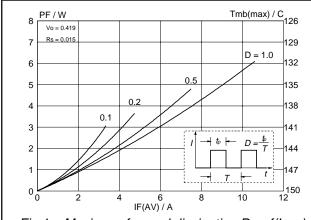


Fig.1. Maximum forward dissipation $P_F = f(I_{F(AV)})$; square current waveform where $I_{F(AV)} = I_{F(RMS)} \times \sqrt{D}$.

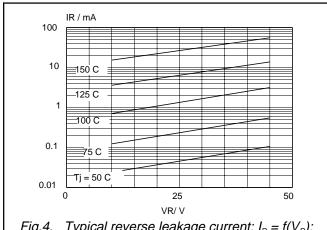


Fig.4. Typical reverse leakage current; $I_R = f(V_R)$; parameter T_i

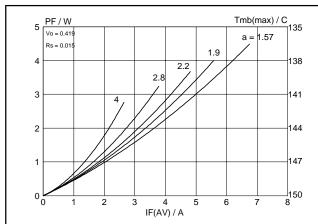


Fig.2. Maximum forward dissipation $P_F = f(I_{F(AV)})$; sinusoidal current waveform where a = form factor = $I_{F(RMS)} / I_{F(AV)}$.

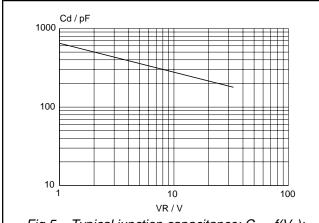


Fig.5. Typical junction capacitance; $C_d = f(V_R)$; f = 1 MHz; $T_j = 25^{\circ}\text{C}$ to 125°C .

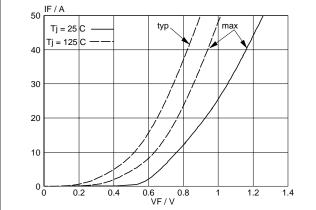


Fig.3. Typical and maximum forward characteristic $I_F = f(V_F)$; parameter T_i

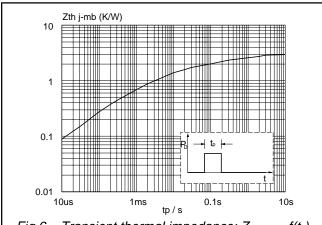
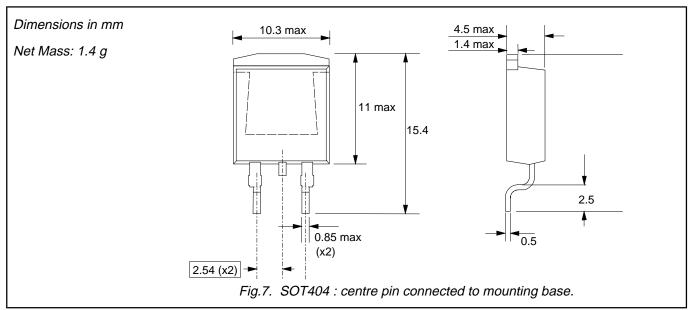


Fig.6. Transient thermal impedance; $Z_{th j-mb} = f(t_p)$.

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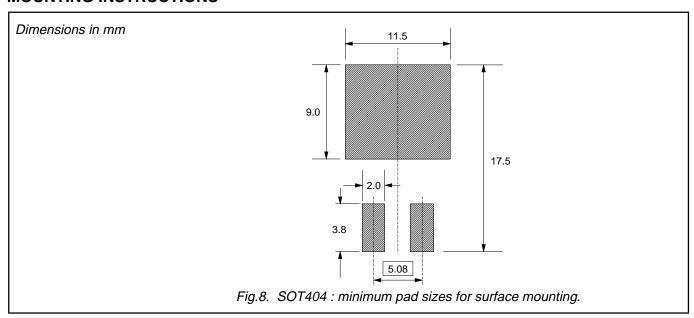
MECHANICAL DATA



Notes

1. Epoxy meets UL94 V0 at 1/8".

MOUNTING INSTRUCTIONS



Notes

1. Plastic meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status				
Objective specification	This data sheet contains target or goal specifications for product development.			
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.			
Product specification	This data sheet contains final product specifications.			

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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